

# DATA SHEET

## **BYC5B-600**

Rectifier diode

Freewheeling and power factor  
correction

Product specification  
File under Discrete Semiconductors, SC02

October 1997

# Rectifier diode

## Freewheeling and power factor correction

**BYC5B-600**

### GENERAL DESCRIPTION

Glass passivated, epitaxial rectifier diode in a plastic envelope suitable for surface mounting. This diode has extremely fast reverse recovery time and low reverse recovery current and is designed specifically for use in forced commutation applications, for example: - as the output rectifier diode in power factor correction circuits operating in continuous conduction mode; or as a freewheeling diode in half-bridge and full-bridge switched mode power supplies.

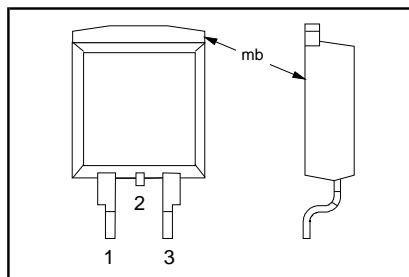
### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
$I_{F(AV)}$	Average forward current		5	A
$V_{RRM}$	Repetitive peak reverse voltage		600	V
$V_F$	Forward voltage		1.75	V
$t_{rr}$	Reverse recovery time	15		ns
$I_{rrm}$	Reverse recovery current		11	A

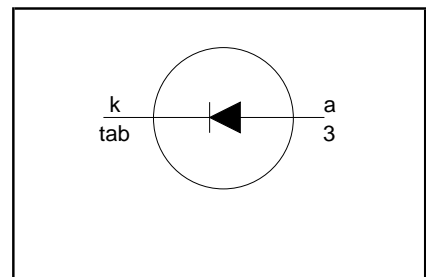
### PINNING - SOT404

PIN	DESCRIPTION
1	no connection
2	cathode
3	anode
mb	cathode

### PIN CONFIGURATION



### SYMBOL



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	Repetitive peak reverse voltage		-	600	V
$V_{RWM}$	Crest working reverse voltage		-	600	V
$V_R$	Continuous reverse voltage		-	500	V
$I_{F(AV)}$	Average forward current	$T_{mb} \leq 110\text{ }^\circ\text{C}^1$ $\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 89\text{ }^\circ\text{C}^1$	-	5	A
$I_{F(RMS)}$	RMS forward current		-	7	A
$I_{FRM}$	Repetitive peak forward current	$\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 89\text{ }^\circ\text{C}^1$	-	10	A
$I_{FSM}$	Non-repetitive peak forward current.	$t = 10\text{ ms}$ $t = 8.3\text{ ms}$ sinusoidal; $T_j = 150\text{ }^\circ\text{C}$ prior to surge with reapplied $V_{RWM(max)}$	-	40 44	A A
$I^2t$	$I^2t$ for fusing	$t = 10\text{ ms}$	-	8	$\text{A}^2\text{s}$
$T_{stg}$	Storage temperature		-40	150	$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150	$^\circ\text{C}$

<sup>1</sup> Maximum mounting base temperature limited by thermal runaway.

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**THERMAL RESISTANCES**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base		-	-	2.5	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	minimum footprint, FR4 board	-	50	-	K/W

**STATIC CHARACTERISTICS**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 5\text{ A}; T_j = 150\text{ }^\circ\text{C}$ $I_F = 10\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	1.4 1.75	1.75 2.2	V V
$I_R$	Reverse current	$I_F = 5\text{ A}; V_R = 600\text{ V}$ $V_R = 500\text{ V}; T_j = 100\text{ }^\circ\text{C}$	-	9 0.9	100 3.0	$\mu\text{A}$ mA

**DYNAMIC CHARACTERISTICS**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$t_{rr}$	Reverse recovery time	$I_F = 5\text{ A to } V_R = 400\text{ V};$ $di_F/dt = 500\text{ A}/\mu\text{s}$	-	19	-	ns
$t_{rr}$	Reverse recovery time	$I_F = 5\text{ A to } V_R = 400\text{ V};$ $di_F/dt = 500\text{ A}/\mu\text{s}; T_j = 125\text{ }^\circ\text{C}$	-	25	30	ns
$I_{rrm}$	Peak reverse recovery current	$I_F = 5\text{ A to } V_R = 400\text{ V};$ $di_F/dt = 500\text{ A}/\mu\text{s}; T_j = 125\text{ }^\circ\text{C}$	-	8	11	A
$V_{fr}$	Forward recovery voltage	$I_F = 10\text{ A}; di_F/dt = 100\text{ A}/\mu\text{s}$	-	9	11	V

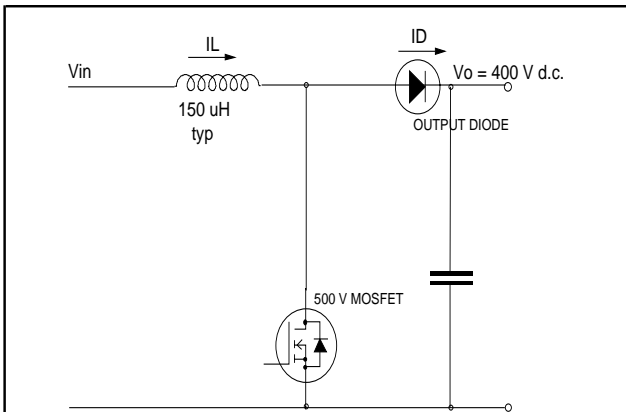


Fig.1. Typical application, output rectifier in boost converter power factor correction circuit. Continuous conduction mode, where the transistor turns on whilst forward current is still flowing in the diode.

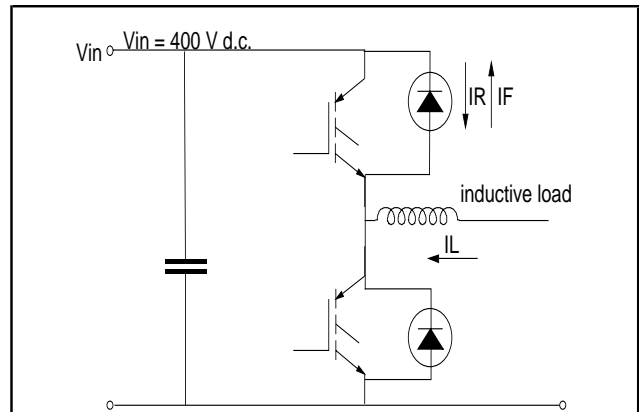


Fig.2. Typical application, freewheeling diode in half bridge converter. Continuous conduction mode, where each transistor turns on whilst forward current is still flowing in the other bridge leg diode.

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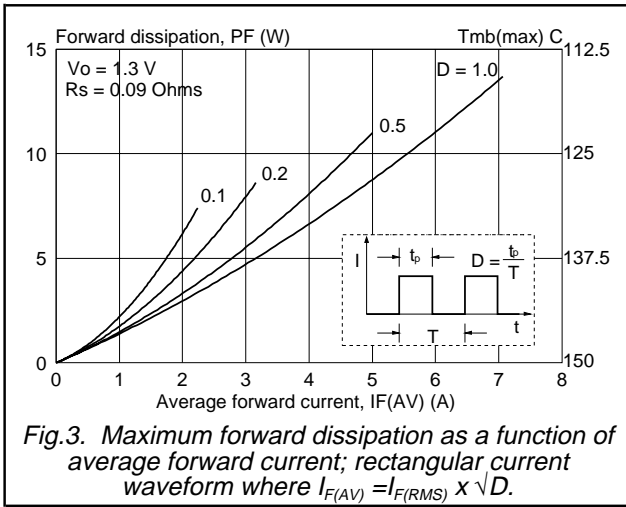


Fig.3. Maximum forward dissipation as a function of average forward current; rectangular current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

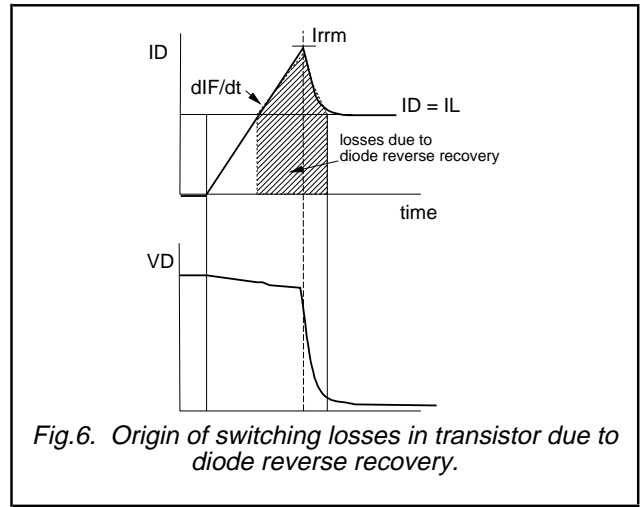


Fig.6. Origin of switching losses in transistor due to diode reverse recovery.

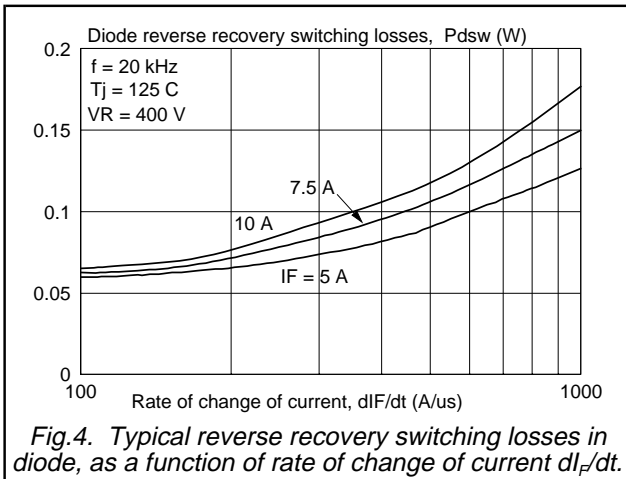


Fig.4. Typical reverse recovery switching losses in diode, as a function of rate of change of current  $dI_F/dt$ .

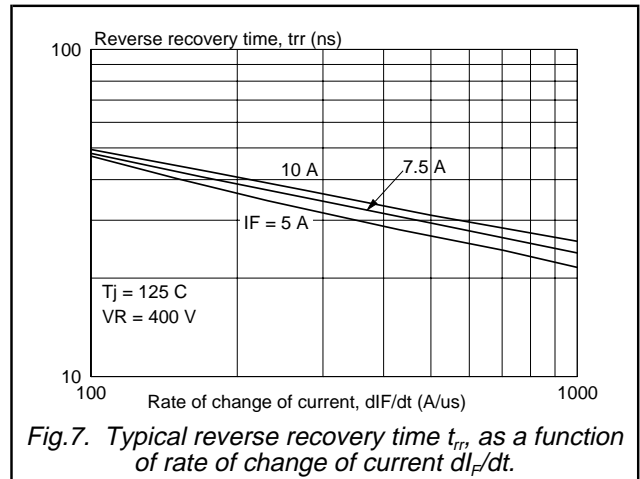


Fig.7. Typical reverse recovery time  $t_{rr}$ , as a function of rate of change of current  $dI_F/dt$ .

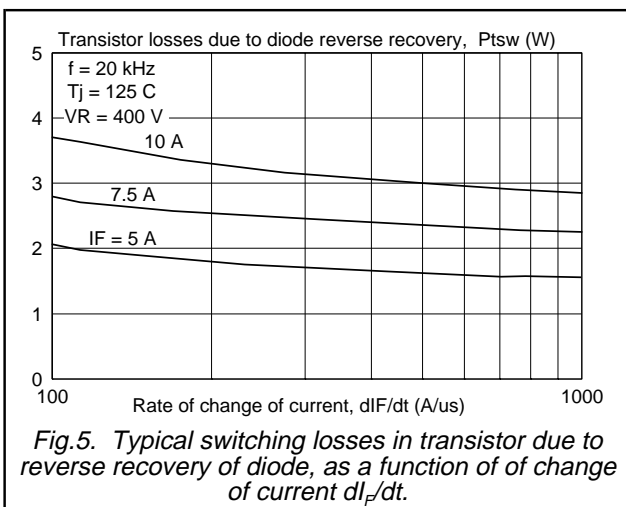


Fig.5. Typical switching losses in transistor due to reverse recovery of diode, as a function of rate of change of current  $dI_F/dt$ .

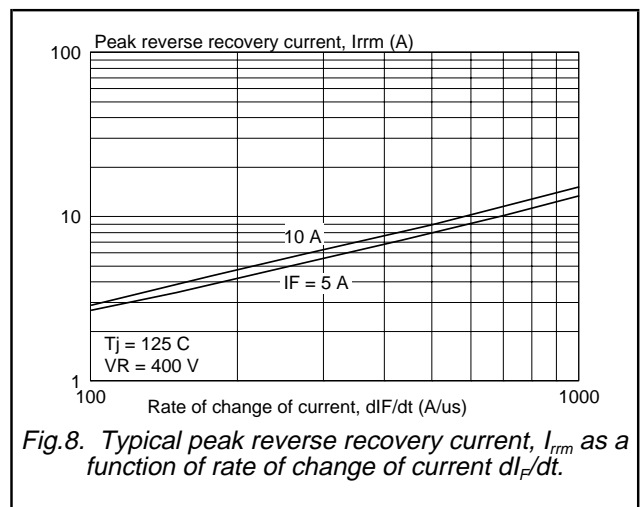
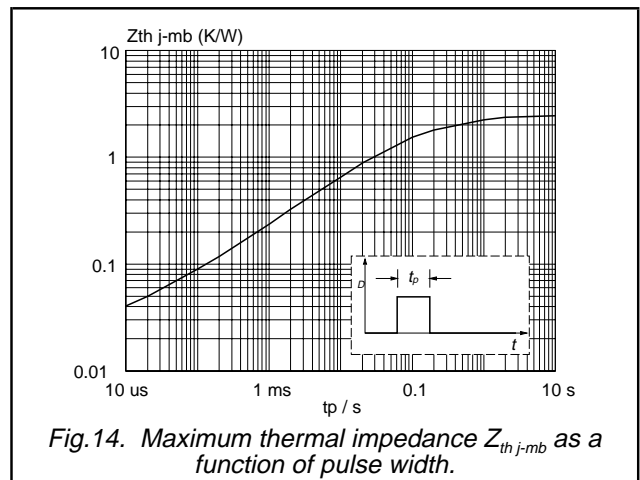
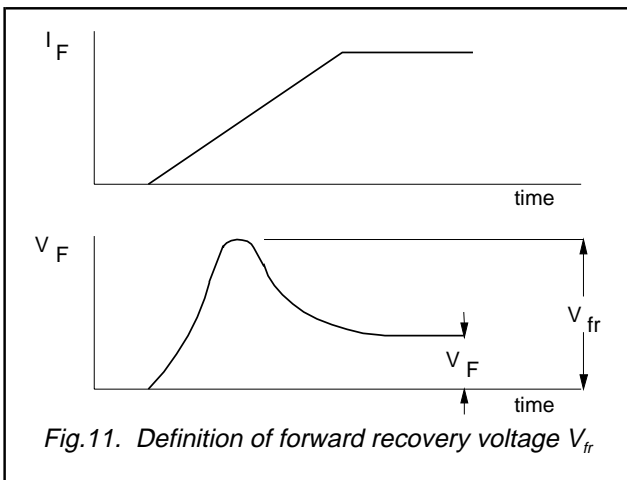
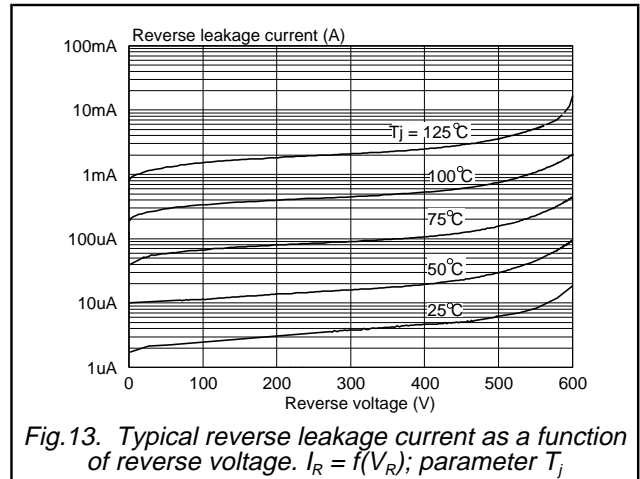
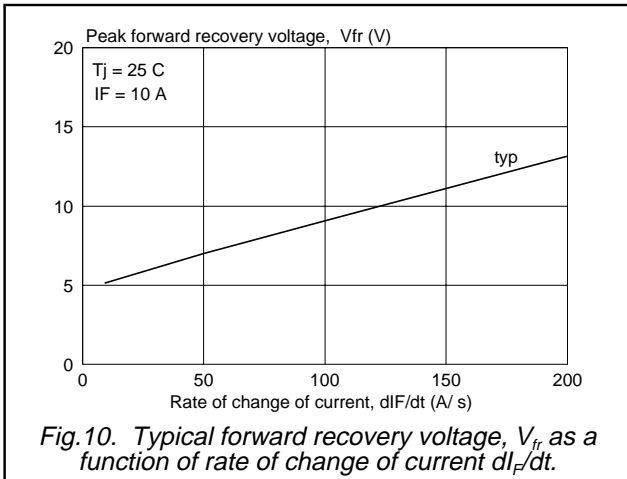
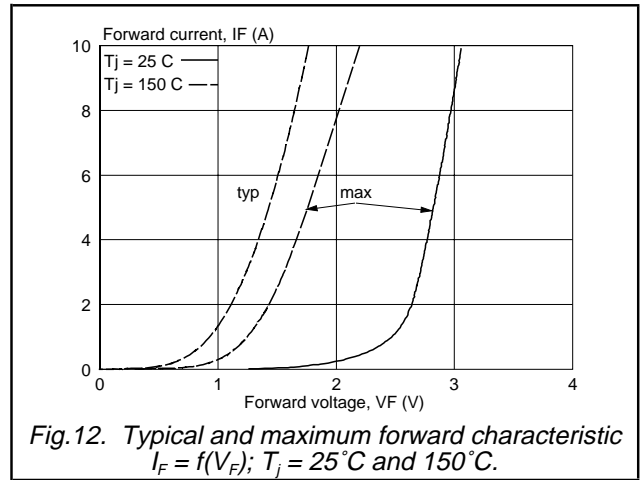
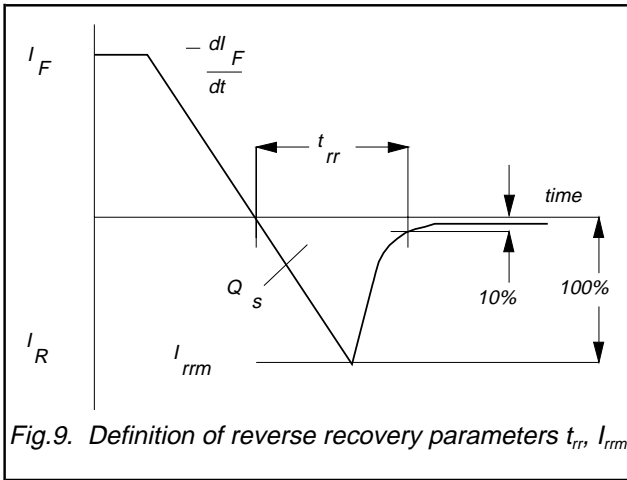


Fig.8. Typical peak reverse recovery current,  $I_{rrm}$ , as a function of rate of change of current  $dI_F/dt$ .

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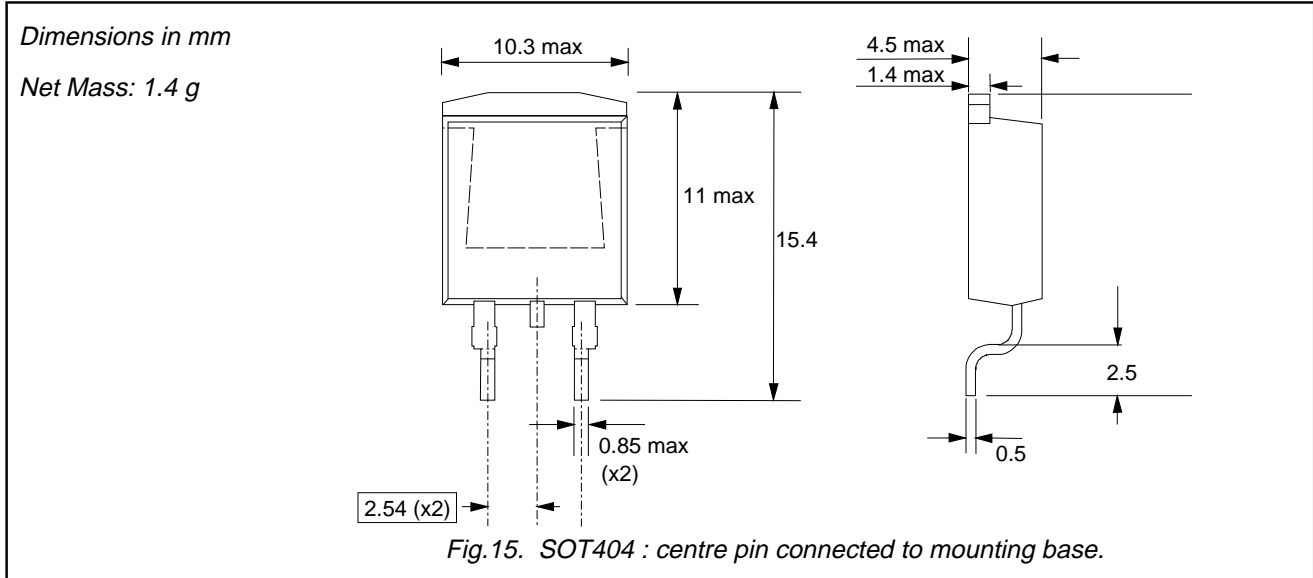
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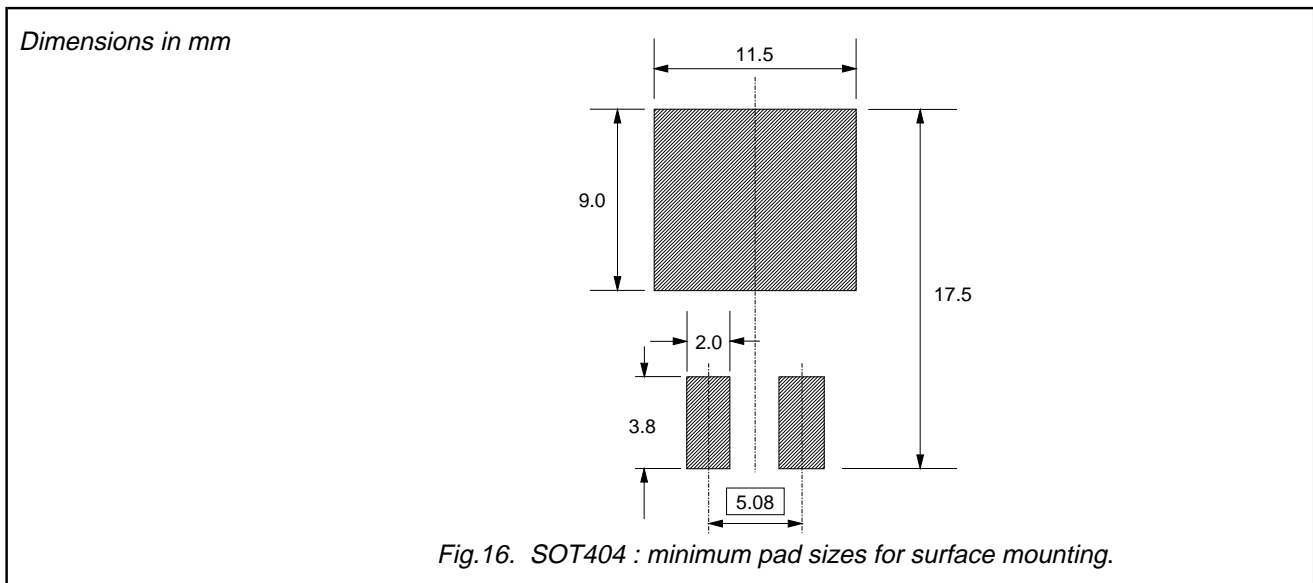
**MECHANICAL DATA**



**Notes**

- 1. Epoxy meets UL94 V0 at 1/8".

**MOUNTING INSTRUCTIONS**



**Notes**

- 1. Plastic meets UL94 V0 at 1/8".

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<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
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Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
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